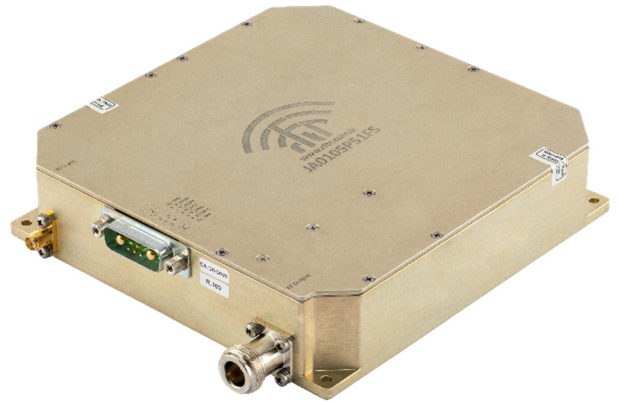




JA01000500P51; 100 MHz – 500 MHz 125W Amplifier

- Solid-state Class AB design
- MOS Transistors
- High reliability and ruggedness
- Ultra Small Dimensions & Ultra Light Weight
- Forward/Reflected Power Monitorings
- Temperature and Current Monitorings
- Enable Control



ELECTRICAL & ENVIRONMENTAL SPECIFICATIONS

Frequency:	100-500 MHz
Output Power:	125 W CW
Nominal Gain:	51 dB
Gain Flatness:	± 2 dB
Input VSWR:	2:1 max.
Load VSWR for Survival:	∞:1 for 1 min.
DC Supply Voltage:	28 V
DC Current:	10 A Avg
Operating Case Temp.:	-40 °C to 85 °C
Storage Temperature:	-40 °C to 85 °C
Shock:	MIL-STD-810F/G
Vibration:	MIL-STD-810F/G

INTERFACES

RF Input:	SMA Female
RF Output:	N Female
7W2 COMBO:	A1) GND
	A2) 28 V
	1) Temperature
	2) Current
	3) Reverse Power
	4) Forward Power
	5) Enable (Active Low)

MECHANICAL SPECIFICATIONS

Size (mm) :	150 x 145 x 34
(inch) :	5.91 x 5.71 x 1.34
Weight :	800 gr.
Plating :	Yellow Chromate

